

RN1701JE(TE85L,F)

RN1701JE(TE85L,F) Information

wurdetsener.com	RN1701JE(TE85L,F) Toshiba Semiconductor and Storage Discrete Semiconductor Products Transistors - Bipolar (BJT) - Arrays, Pre-Biased TRANS 2NPN PREBIAS 0.1W ESV SOT-553 For the pricing/inventory/lead time, please contact	
For Reference Only	us Website: https://www.heisener.com E-mail: salesdept@heisener.com	Request a Quote

E-mail: salesdept@heisener.com

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



RN1701JE(TE85L,F) Specifications

	Report errors?	
Supplier Device Package	ESV	
Package / Case	SOT-553	
Mounting Type	Surface Mount	
Power - Max	100mW	
Frequency - Transition	250MHz	
Current - Collector Cutoff (Max)	100nA (ICBO)	
Vce Saturation (Max) @ Ib, Ic	300mV @ 250µA, 5mA	
DC Current Gain (hFE) (Min) @ Ic, Vce	30 @ 10mA, 5V	
Resistor - Emitter Base (R2) (Ohms)	4.7k	
Resistor - Base (R1) (Ohms)	4.7k	
Voltage - Collector Emitter Breakdown (Max)	50V	
Current - Collector (Ic) (Max)	100mA	
Transistor Type	2 NPN - Pre-Biased (Dual) (Emitter Coupled)	
Series	-	
Package	SOT-553	
	Transistors - Bipolar (BJT) - Arrays, Pre-Biased	
Category	Discrete Semiconductor Products	
Manufacturer	Toshiba Semiconductor and Storage	
Manufacturer Part Number	RN1701JE(TE85L,F)	

RN1701JE(TE85L,F) Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

SERVICE BUARANTEE

Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

RN1701JE(TE85L,F) Payment Methods





If you have any question about RN1701JE(TE85L,F), please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com